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**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicants: Toshiharu Furukawa, et al. Confirmation No. 5763  
Serial No.: 10/711,764  
Filing Date: October 4, 2004  
Examiner: Jarrett J. Stark  
Art Unit: 2823  
Title: **LOW-K DIELECTRIC LAYER BASED UPON CARBON NANOTUBES** (formerly entitled **LOW-K DIELECTRIC MATERIAL BASED UPON CARBON NANOTUBES**)  
Atty. Docket No.: BUR920040152US1

**AMENDMENT UNDER 37 C.F.R. § 1.116**

Mail Stop AMENDMENT  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In reply to the final Office Action dated April 13, 2006, please amend the above-identified application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims that begins on page 3 of this paper.

**Remarks** begin on page 7 of this paper.